

C4D20120A

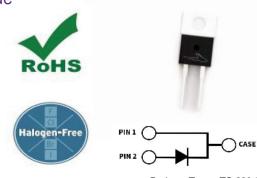
4th Generation 1200 V, 20 A Silicon Carbide Schottky Diode

Description

With the performance advantages of a Silicon Carbide (SiC) Schottky Barrier diode, power electronics systems can expect to meet higher e iciency standards than Si-based solutions, while also reaching higher frequencies and power densities. SiC diodes can be easily paralleled to meet various application demands, without concern of thermal runaway. In combination with the reduced cooling requirements and improved thermal performance of SiC products, SiC diodes are able to provide lower overall system costs in a variety of diverse applications.



- Low Forward Voltage (V_F) Drop with Positive Temperature Coe icient
- Zero Reverse Recovery Ourrent / Forward Recovery Voltage
- Temperature-Independent Switching Behavior



Package Types: TO-220-2 Marking: C4D20120A

Applications

- Industrial Switched Mode Power Supplies
- Uninterruptible & AUX Power Supplies
- Boost for PFC & DC-DC Stages
- Solar Inverters

Maximum Ratings ($T_c = 25^{\circ}C$ Unless Otherwise Specified)

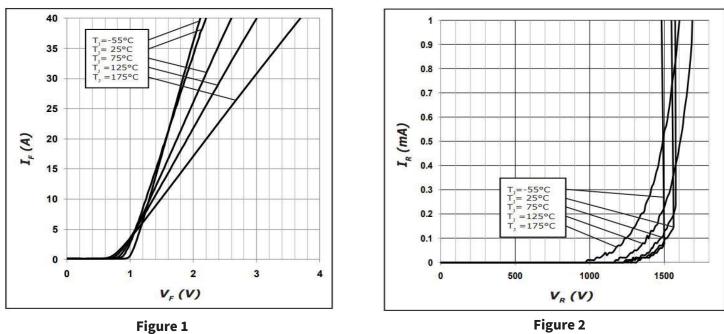
Parameter	Symbol	Value	Unit	Test Conditions	Notes	
Repetitive Peak Reverse Voltage	V _{RRM}	1200				
DC Blocking Voltage	V _{DC}	1200	V			
Continuous Forward Current	I _F	54.5		T _j = 25 °C		
		26	A	T _j = 135 °C	Fig. 3	
		20		T _J = 150 °C		
Repetitive Peak Forward Surge Current	I _{FRM}	91		$T_c = 25 \text{ °C}, t_p = 10 \text{ ms}, \text{ Half Sine Wave}$		
		61		$T_c = 110 \text{ °C}, t_p = 10 \text{ ms}, \text{ Half Sine Wave}$		
Non-Repetitive Forward Surge Current	I _{FSM}	130		$T_c = 25 \text{ °C}, t_p = 10 \text{ ms}, \text{ Half Sine Wave}$	F = 0	
		110		$T_c = 110 \text{ °C,} t_p = 10 \text{ ms}, \text{ Half Sine Wave}$	Fig. 8	
Non-Repetitive Peak Forward Surge Current	_{F,Max}	1150		$T_{c} = 25 \text{ °C}, t_{p} = 10 \mu \text{s}, \text{ Pulse}$		
		950		$T_{c} = 110^{\circ}C, t_{p} = 10 \mu s, Pulse$		
Power Dissipation	P _{tot}	250	W	$T_{J} = 25 \text{ °C}$	Fig. 4	
		112.5		T _J = 110 °C		
i²t Value	i²t	84.5	A ² s	$T_{c} = 25 \text{ °C}, t_{p} = 10 \text{ ms}$		
		60.5		$T_{c} = 110^{\circ}C, t_{p} = 10 \text{ ms}$		



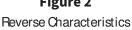
Electrical Characteristics

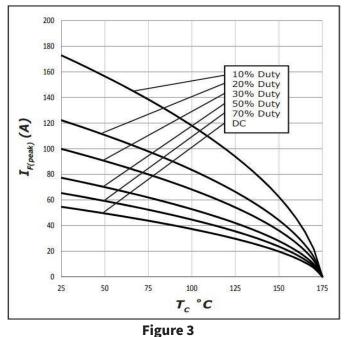
Parameter	Symbol	Тур.	Max.	Unit	Test Conditions	Notes
Forward Voltage		1.5	1.8	v	I _F = 20 A, T _j = 25 °C	— Fig. 1
	V _F	2.2	3		I _F = 20 A, T _j = 175 °C	
Reverse Current		35	200	μA	V _R = 1200 V, T _j = 25 °C	
	I _R	65	400		V _R = 1200 V, T _j = 175 °C	Fig. 2
Total Capacitive Charge	Q _c	99		nC	$V_{R} = 800 \text{ V}, T_{j} = 25 \text{ °C}$	Fig. 5
		1500			$V_{\rm R} = 0$ V, $T_{\rm j}$	
Total Capacitance	С			pF		

Typical Performance



Forward Characteristics





Current Derating

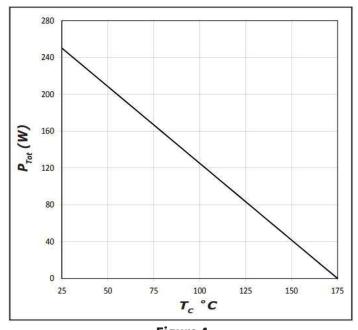


Figure 4 Power Derating

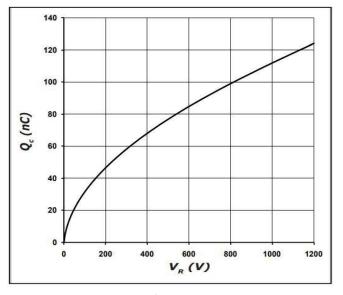


Figure 5 Total Capacitance vs. Reverse Voltage

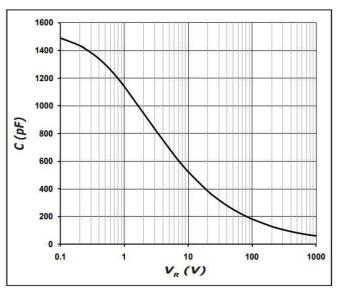


Figure 6 Capacitace vs. Reverse Voltage

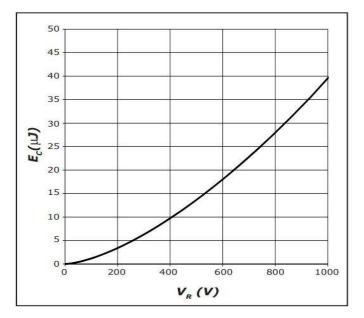


Figure 7 Capacitance Stored Energy

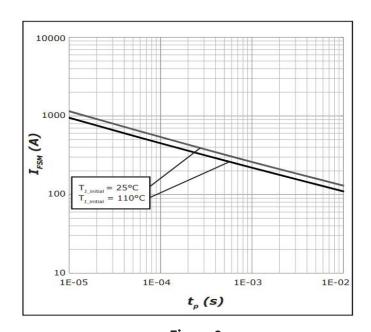


Figure 8 Non-Repetitive Peak Forward Surge Current versus Pulse Duration (sinusoidal waveform)

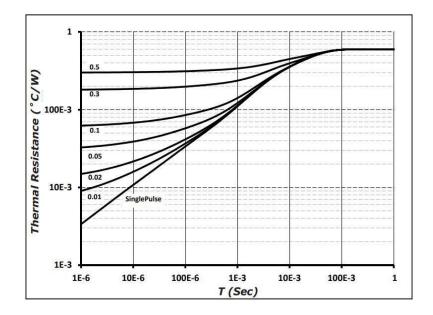
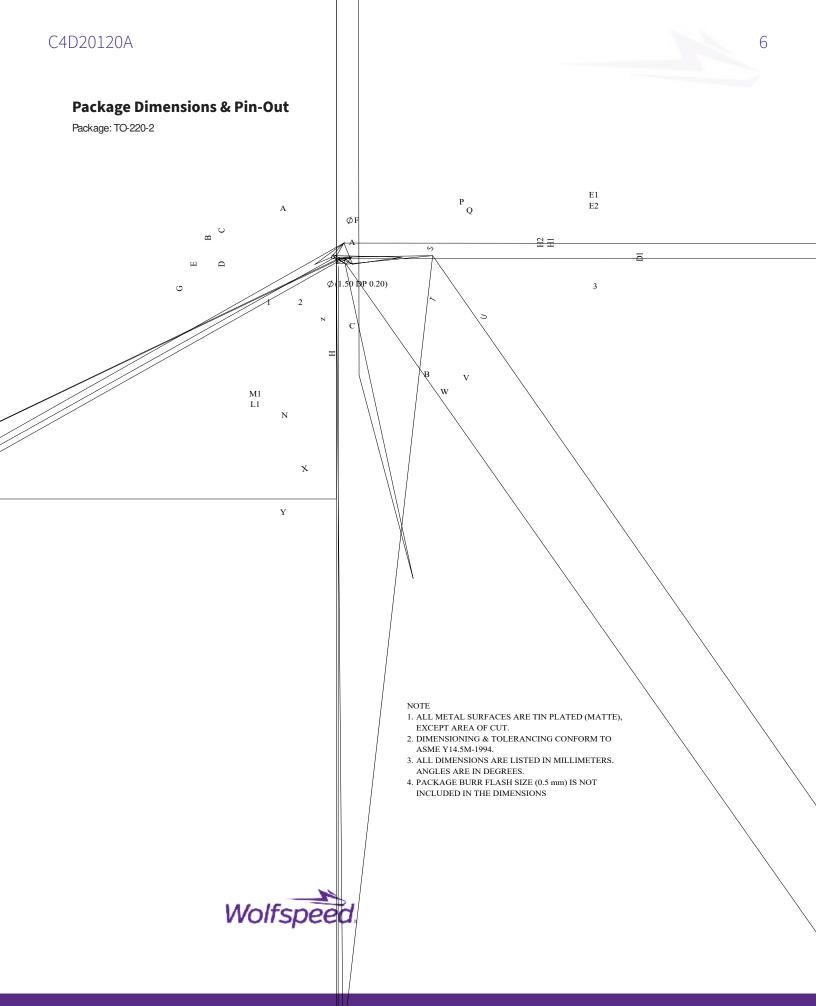


Figure 9 Transient Thermal Impedance

5

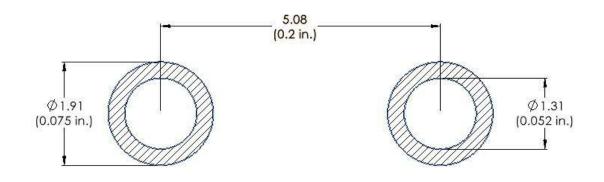






Recommended Solder Pad Layout

Primary dimensions shown in mm. Learn more about recommended soldering profiles in this application note.



Product Ordering Information

Order Number	Packing Type		
C4D20120A	Tube		

Learn more about power device packing & shipment information in this application note.



Revision History

Document Version	Date of Release	Description of Changes
1	October-2016	Initial Release
6	March-2023	Update Package Drawing Update Landing Pad



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